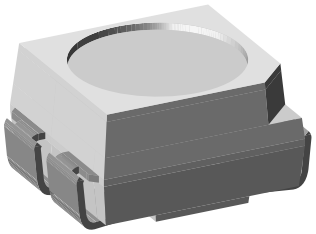
Bicolor SMD LED PLCC-4



19211

DESCRIPTION

These devices have been designed to meet the increasing demand for surface mounting technology.

The package of the VLMKE340. is the PLCC-4.

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

This SMD device consists of a red and yellow chip. So it is possible to choose the color in one device.

PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD PLCC-4
- Product series: bicolor
- Angle of half intensity: ± 60°

FEATURES

- SMD LED with exceptional brightness
- Multicolored
- Luminous intensity categorized
- EIA and ICE standard package
- Compatible with automatic placement equipment
- Suitable for IR reflow and TTW soldering
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit $I_{Vmax.}/I_{Vmin.} \leq 1.6$
- JEDEC level 4
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free

e3

RoHS COMPLIANT

HALOGEN FREE GREEN (5-2008)

APPLICATIONS

- Telecommunication: indicator and backlighting in telephone and fax
- Indicator and backlight for audio and video equipment
- Indicator and backlight in office equipment
- Flat backlight for LCDs, switches, and symbols
- General use

PARTS TABLE

PART	COLOR	LUMINOUS INTENSITY (mcd)			at I_F (mA)	WAVELENGTH (nm)			at I_F (mA)	FORWARD VOLTAGE (V)			at I_F (mA)	TECHNOLOGY
		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.		
VLMKE3400-GS08	Red	56	-	180	20	-	630	-	20	-	1.9	2.6	20	AlInGaP on GaAs
VLMKE3400-GS08	Yellow	90	-	280	20	581	588	594	20	-	2	2.6	20	AlInGaP on GaAs
VLMKE3400-GS18	Red	56	-	180	20	-	630	-	20	-	1.9	2.6	20	AlInGaP on GaAs
VLMKE3400-GS18	Yellow	90	-	280	20	581	588	594	20	-	2	2.6	20	AlInGaP on GaAs
VLMKE3401-GS08	Red	71	-	140	20	-	630	-	20	-	1.9	2.6	20	AlInGaP on GaAs
VLMKE3401-GS08	Yellow	112	-	224	20	581	588	594	20	-	2	2.6	20	AlInGaP on GaAs
VLMKE3401-GS18	Red	71	-	140	20	-	630	-	20	-	1.9	2.6	20	AlInGaP on GaAs
VLMKE3401-GS18	Yellow	112	-	224	20	581	588	594	20	-	2	2.6	20	AlInGaP on GaAs

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)
VLMKE3400, VLMKE3401

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage per diode		V_R	Not designed for reverse operation	V
DC forward current per diode	$T_{amb} \leq 80$ °C, 1 chip on	I_F	30	mA
Surge forward current per diode	$t_p \leq 10$ µs	I_{FSM}	0.1	A
Power dissipation per diode		P_V	80	mW
Junction temperature		T_j	125	°C
Operating temperature range		T_{amb}	-40 to +100	°C
Storage temperature range		T_{stg}	-40 to +100	°C
Thermal resistance junction / ambient	Mounted on PC board (pad size > 16 mm²)	R_{thJA}	560	K/W

OPTICAL AND ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)
VLMKE3400, VLMKE3401, RED

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I_F = 20 mA	VLMKE3400	I_V	56	-	180	mcd
		VLMKE3401	I_V	71	-	140	mcd
Dominant wavelength	I_F = 20 mA		λ_d	-	630	-	nm
Peak wavelength	I_F = 20 mA		λ_p	-	643	-	nm
Angle of half intensity	I_F = 20 mA		φ	-	± 60	-	deg
Forward voltage	I_F = 20 mA		V_F	-	1.9	2.6	V
Reverse voltage	I_R = 10 µA		V_R	6	-	-	V
Junction capacitance	V_R = 0 V, f = 1 MHz		C_j	-	15	-	pF

OPTICAL AND ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)
VLMKE3400, VLMKE3401, YELLOW

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I_F = 20 mA	VLMKE3400	I_V	90	-	280	mcd
		VLMKE3401	I_V	112	-	224	mcd
Dominant wavelength	I_F = 20 mA		λ_d	581	588	594	nm
Peak wavelength	I_F = 20 mA		λ_p	-	590	-	nm
Angle of half intensity	I_F = 20 mA		φ	-	± 60	-	deg
Forward voltage	I_F = 20 mA		V_F	-	2	2.6	V
Reverse voltage	I_R = 10 µA		V_R	6	-	-	V
Junction capacitance	V_R = 0 V, f = 1 MHz		C_j	-	15	-	pF

LUMINOUS INTENSITY CLASSIFICATION AND GROUP COMBINATIONS VLMKE34..

		RED				
		P2 56 mcd to 71 mcd	Q1 71 mcd to 90 mcd	Q2 90 mcd to 112 mcd	R1 112 mcd to 140 mcd	R2 140 mcd to 80 mcd
YELLOW	Q2 90 mcd to 112 mcd	00	00	00	00	00
	R1 112 mcd to 140 mcd	00	00 01	00 01	00 01	00
	R2 140 mcd to 180 mcd	00	00 01	00 01	00 01	00
	S1 180 mcd to 224 mcd	00	00 01	00 01	00 01	00
	S2 224 mcd to 280 mcd	00	00	00	00	00

Notes

- Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %.The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel). In order to ensure availability, single brightness groups will not be orderable.In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel. In order to ensure availability, single wavelength groups will not be orderable.

(1) Followed by 00 or 01

COLOR CLASSIFIATION

GROUP	DOMINANT WAVELENGTH (nm)	
	YELLOW	
	MIN.	MAX.
1	581	584
2	583	586
3	585	588
4	587	590
5	589	592
6	591	594

Note

- Wavelengths are tested at a current pulse duration of 25 ms.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

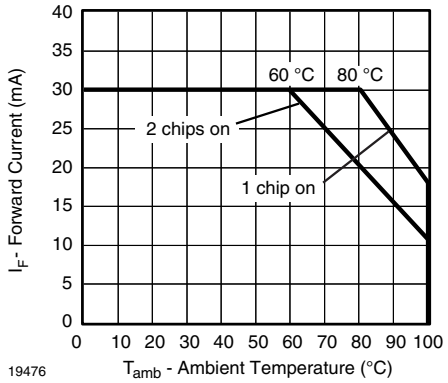


Fig. 1 - Forward Current vs. Ambient Temperature for InGaN

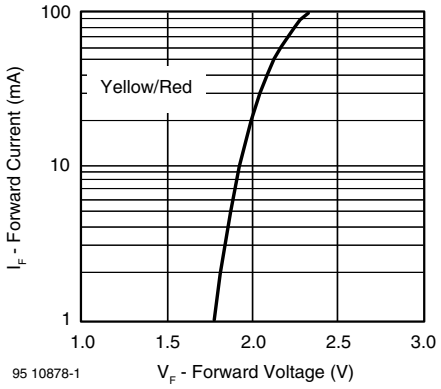


Fig. 4 - Forward Current vs. Forward Voltage

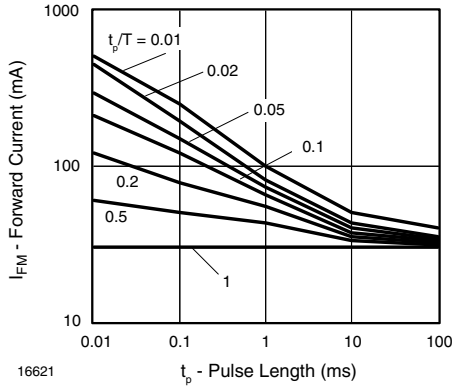


Fig. 2 - Forward Current vs. Pulse Duration

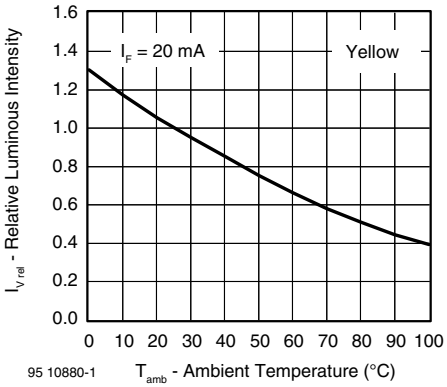


Fig. 5 - Relative Luminous Intensity vs. Ambient Temperature

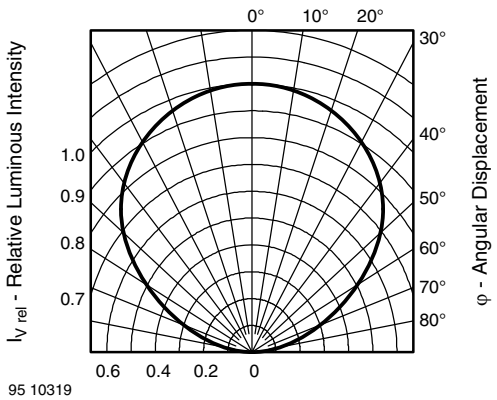


Fig. 3 - Relative Luminous Intensity vs. Angular Displacement

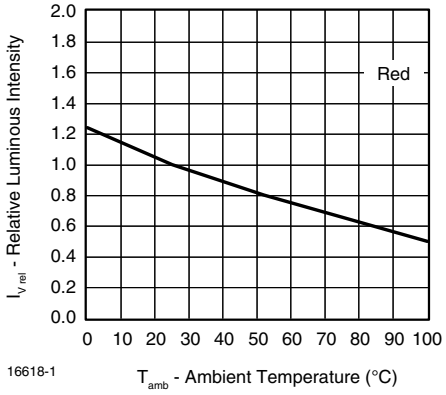


Fig. 6 - Relative Luminous Intensity vs. Ambient Temperature

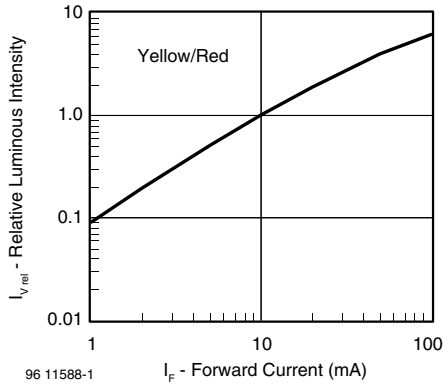


Fig. 7 - Relative Luminous Intensity vs. Forward Current

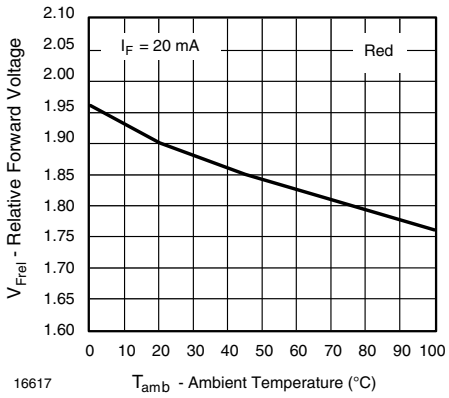


Fig. 10 - Relative Forward Voltage vs. Ambient Temperature

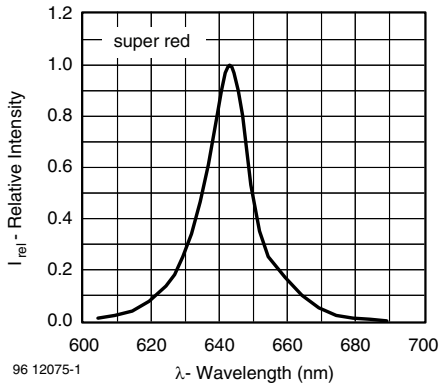


Fig. 8 - Relative Intensity vs. Wavelength

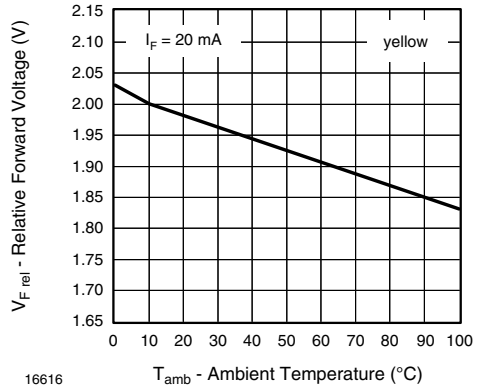


Fig. 11 - Relative Forward Voltage vs. Ambient Temperature

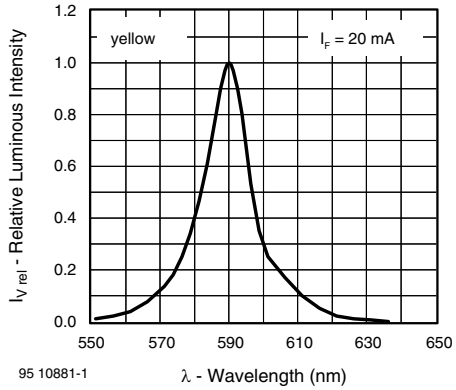
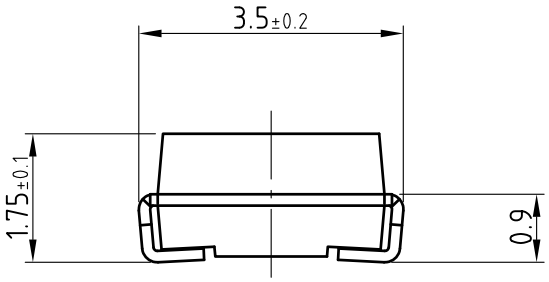
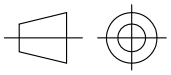


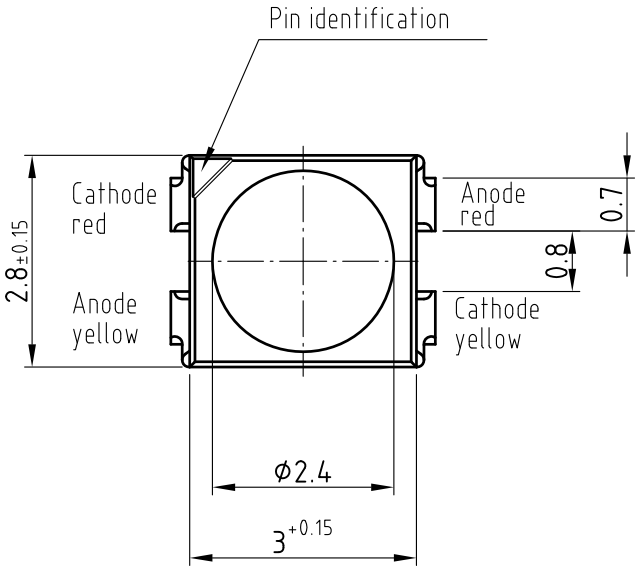
Fig. 9 - Relative Intensity vs. Wavelength

PACKAGE DIMENSIONS in millimeters

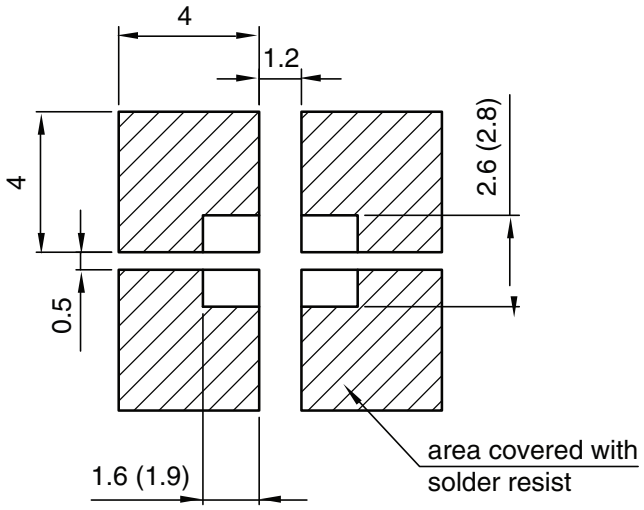




technical drawings
according to DIN
specifications



Mounting Pad Layout



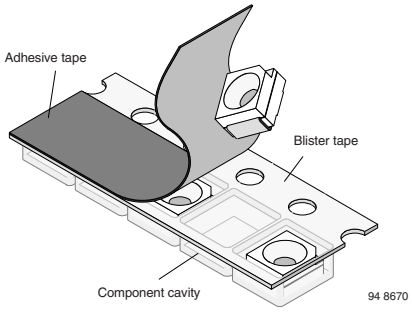
Dimensions: IR and Vaporphase
(Wave Soldering)

Drawing-No.: 6.541-5057.01-4
Issue: 5; 30.05.07
19899

METHOD OF TAPING / POLARITY AND TAPE AND REEL

SMD LED (VLM.3 - SERIES)

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



TAPING OF VLM.3...

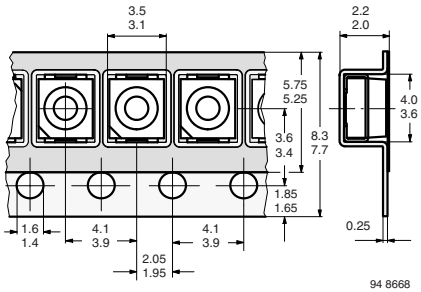


Fig. 12 - Tape Dimensions in mm for PLCC-2

REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDS, TAPE OPTION GS08 (= 1500 PCS.)

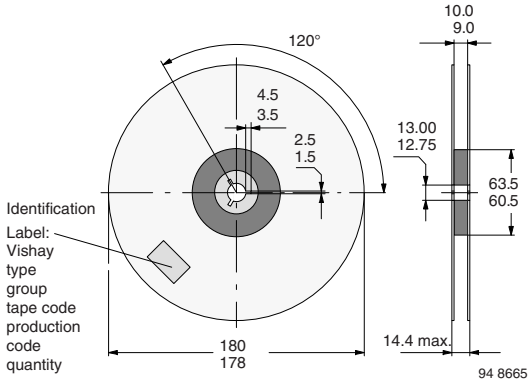


Fig. 13 - Reel Dimensions - GS08

REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDS, TAPE OPTION GS18 (= 8000 PCS.) PREFERRED

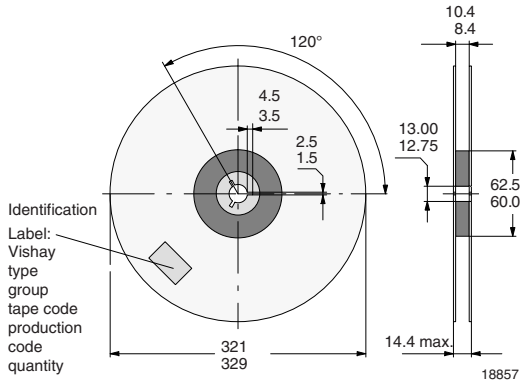


Fig. 14 - Reel Dimensions - GS18

SOLDERING PROFILE

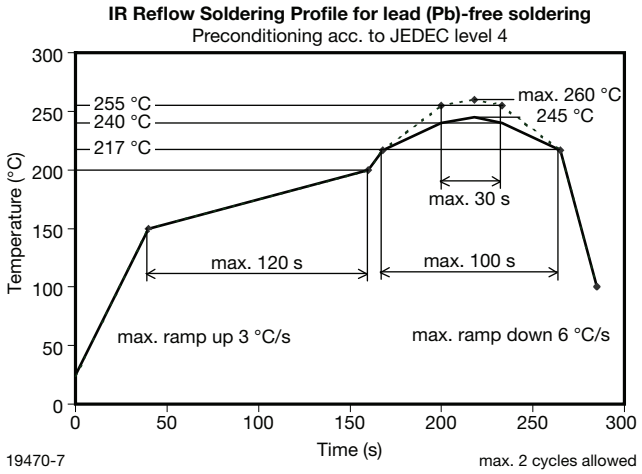


Fig. 15 - Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020)

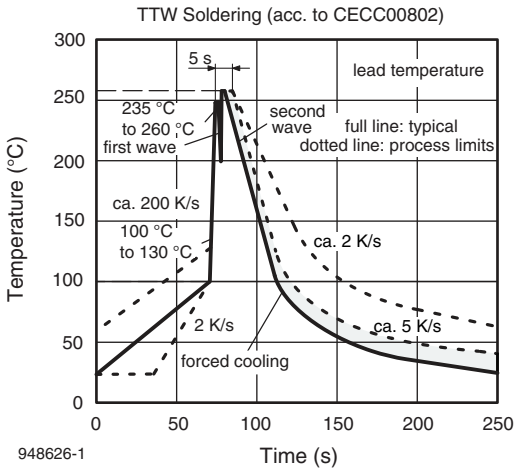
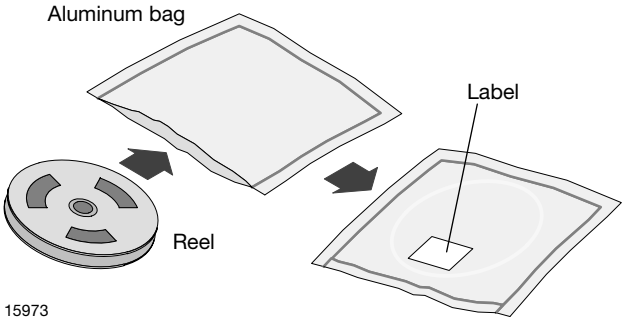


Fig. 16 - Double Wave Soldering of Opto Devices (all Packages)

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



15973

FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

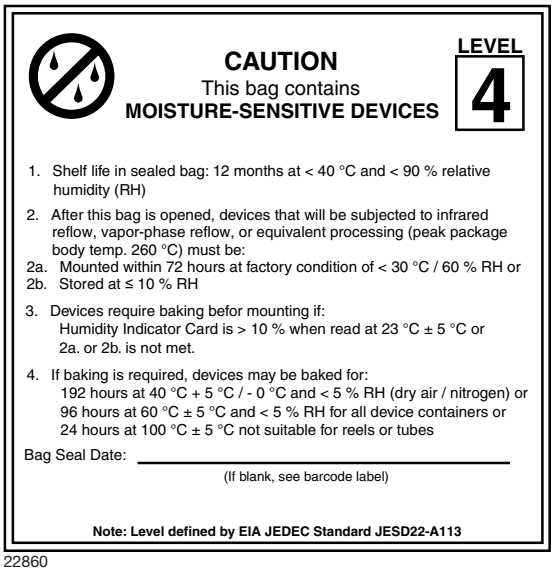
- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 72 h under these conditions moisture content will be too high for reflow soldering.

In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C / - 0 °C and < 5 % RH (dry air / nitrogen) or
96 h at 60 °C + 5 °C and < 5 % RH for all device containers or
24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 4 label is included on all dry bags.



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Example of JESD22-A112 level 4 label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.

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